

## PDF hosted at the Radboud Repository of the Radboud University Nijmegen

The following full text is a publisher's version.

For additional information about this publication click this link.

<http://hdl.handle.net/2066/140112>

Please be advised that this information was generated on 2017-12-05 and may be subject to change.

## Probing of valley polarization in graphene via optical second-harmonic generation

T. O. Wehling,<sup>1,2,\*</sup> A. Huber,<sup>3</sup> A. I. Lichtenstein,<sup>3</sup> and M. I. Katsnelson<sup>4</sup>

<sup>1</sup>*Institut für Theoretische Physik, Universität Bremen, Otto-Hahn-Allee 1, 28359 Bremen, Germany*

<sup>2</sup>*Bremen Center for Computational Materials Science, Universität Bremen, Am Fallturm 1a, 28359 Bremen, Germany*

<sup>3</sup>*I. Institut für Theoretische Physik, Universität Hamburg, Jungiusstraße 9, D-20355 Hamburg, Germany*

<sup>4</sup>*Radboud University of Nijmegen, Institute for Molecules and Materials, Heijendaalseweg 135, 6525 AJ Nijmegen, The Netherlands*

(Received 25 July 2014; revised manuscript received 27 October 2014; published 9 January 2015)

Valley polarization in graphene breaks inversion symmetry and therefore leads to second-harmonic generation. We present a complete theory of this effect within a single-particle approximation. It is shown that this may be a sensitive tool to measure the valley polarization created, e.g., by polarized light and, thus, can be used for the development of ultrafast valleytronics in graphene.

DOI: [10.1103/PhysRevB.91.041404](https://doi.org/10.1103/PhysRevB.91.041404)

PACS number(s): 78.67.Wj, 42.65.Ky

The unique electronic properties of graphene [1–3] open ways for many interesting and unusual applications. In particular, a concept of *valleytronics* was suggested [4], that is, a manipulation of valley degree of freedom (conical points  $K$  and  $K'$ ), in analogy with the well-known field of spintronics [5]. Up to now, many different ways for the creation of the valley polarization in graphene have been proposed (see, e.g., Refs. [6–8]). At the same time, *detection* of the valley polarization is a tricky issue. The first suggestion, the use of a superconducting current through graphene [9], does not look suitable for practical applications, e.g., due to a requirement of low temperatures. It was mentioned in Ref. [7] that the breaking of inversion symmetry by the valley polarization can be probed via second-harmonic generation (SHG), a well-known nonlinear optical effect [10]. Together with their suggestion to use linearly polarized light to create the valley polarization (recently, it was experimentally realized for another two-dimensional crystal,  $\text{MoS}_2$  [11,12], with circularly polarized light) it would open a way to ultrafast valleytronics where all manipulations with the valley degree of freedom are performed via short laser pulses, as illustrated in Fig. 1. In spintronics, this is now one of the most prospective lines of development [13].

There is, however, a problem. SHG is related to the term in the current density  $\vec{j}$  proportional to the square of the electric field  $\vec{E}$ :

$$j_\alpha = \chi_{\alpha\beta\gamma} E_\beta E_\gamma. \quad (1)$$

For a system with inversion center  $\hat{\chi} = 0$ . This does not mean, however, that SHG is impossible since the photon wave vector  $\vec{q}$  plays the role of a factor violating inversion symmetry, and there is a contribution to the current

$$j_\alpha = \phi_{\alpha\beta\gamma\delta} E_\beta E_\gamma q_\delta. \quad (2)$$

For the case of graphene and other two-dimensional electron systems it was calculated in Ref. [14]. In comparison with Eq. (1) it contains a relativistic smallness parameter  $v_F/c \approx 1/300$  where  $v_F$  is the Fermi velocity and  $c$  is the velocity of light. At the same time, the current in Eq. (1) is expected to be proportional to the valley polarization. The order of magnitude

of the valley polarization which can be really probed via SHG depends on explicit values of the tensor  $\hat{\chi}$ , which will be calculated in this work.

Valley polarization can refer either to different occupations or to different current densities due to electrons from the  $K$  and  $K'$  valleys [4]. In the following, we consider different occupations in the  $K$  and  $K'$  valleys, which corresponds to different chemical potentials  $\mu \pm \delta\mu$ , as illustrated in Fig. 1. Possibilities to generate this kind of valley polarization include quantum pumping [8], nonuniform valley current densities [4] as well as valley Hall effects [15].

We start with a derivation of the effective Hamiltonian of electron-photon interaction for the case of graphene (c.f., e.g., Refs. [3,16]), as the case of nonlinear optics requires special care. Let us consider a general Hamiltonian of band electrons in electromagnetic field described by the vector potential  $\mathbf{A}(\mathbf{r}, t)$ :

$$H = \sum_{ij, LL', \sigma} t_{ij}^{L'L} \exp\left(i \frac{e}{c} \int_{\mathbf{R}_{jL'}}^{\mathbf{R}_{iL}} d\mathbf{r} \mathbf{A}(\mathbf{r}, t)\right) c_{iL\sigma}^\dagger c_{jL'\sigma}, \quad (3)$$

where  $\mathbf{R}_{iL}$  is the atomic position and  $L = (n, l, m, \gamma)$  is a combined index of quantum numbers of atom  $\gamma$  (in the equations we assume  $\hbar = 1$ ). The atomic positions can be separated into two parts

$$\mathbf{R}_{iL} = \mathbf{R}_i + \rho_L, \quad (4)$$

where the former indexes the unit cell  $i$  and the latter the atom  $L$  within the cell in the case of a multiatomic unit cell (like the honeycomb lattice of graphene). We assume, as usual, that the interaction with the electromagnetic field is taken into account via Peierls substitution

$$c_{iL\sigma}^\dagger \rightarrow c_{iL\sigma}^\dagger \exp\left(i \frac{e}{c} \int^{\mathbf{R}_{iL}} d\mathbf{r} \mathbf{A}(\mathbf{r}, t)\right) \quad (5)$$

for the electron creation operators  $c_{iL\sigma}^\dagger$  and similarly for the electron annihilation operators  $c_{iL\sigma}$ .  $t_{ij}^{L'L}$  are the parameters of the band-structure Hamiltonian.

Since we are interested in terms up to second order in the vector potential we expand the hopping and treat the additional terms proportional to the vector potential as perturbation. The

\*wehling@itp.uni-bremen.de

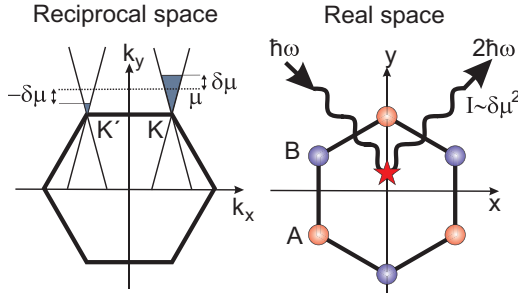


FIG. 1. (Color online) Illustration of second-harmonic generation in graphene. SHG requires breaking of inversion symmetry which can be achieved through valley polarization as illustrated in the left panel. Valley polarization is modeled in terms of different chemical potentials  $\mu \pm \delta\mu$  in valleys  $K$  and  $K'$ . With the choice of the coordinate system illustrated in the right panel, valley polarization breaks the  $x \rightarrow -x$  mirror symmetry. The second-harmonic intensity  $I$  is proportional to  $\delta\mu^2$ .

Hamiltonian then becomes

$$\begin{aligned}
 H &\equiv H^{(0)} + H^{(1)} + H^{(2)} + O(\mathbf{A}^3) \\
 &= \sum_{ij,LL',\sigma} t_{ij}^{L'L} c_{iL'\sigma}^\dagger c_{jL\sigma} + i \frac{e}{c} A_\alpha(t) \\
 &\quad \times \sum_{ij,LL',\sigma} t_{ij}^{L'L} (R_{iL'\alpha} - R_{jL\alpha}) c_{iL'\sigma}^\dagger c_{jL\sigma} \\
 &\quad + \frac{1}{2} \left( i \frac{e}{c} \right)^2 A_\alpha(t) A_\beta(t) \sum_{ij,LL',\sigma} t_{ij}^{L'L} (R_{iL'\alpha} \\
 &\quad - R_{jL\alpha})(R_{iL'\beta} - R_{jL\beta}) c_{iL'\sigma}^\dagger c_{jL\sigma} + O(\mathbf{A}^3), \quad (6)
 \end{aligned}$$

where the second equation is defined in powers of the vector potential and we further assumed that the vector potential slowly varies in  $\mathbf{r}$ . With a basis transformation to Bloch waves  $c_{\mathbf{k}L\sigma} = \frac{1}{\sqrt{N}} \sum_j \exp(i\mathbf{k}\mathbf{R}_j) c_{jL\sigma}$  the bare part of the Hamiltonian is diagonalized according to  $H^{(0)} = \sum_{\mathbf{k},LL',\sigma} H_{\mathbf{k},LL'}^0 c_{\mathbf{k}L\sigma}^\dagger c_{\mathbf{k}L'\sigma}$  with

$$H_{\mathbf{k},LL'}^0 = \sum_{ij} t_{ij}^{L'L} \exp[-i\mathbf{k}(\mathbf{R}_i - \mathbf{R}_j)]. \quad (7)$$

Now one can distinguish between two currents which are defined using the Hamiltonian (6) by

$$j_\alpha^{(1)} \equiv \left. \frac{\delta H}{\delta A_\alpha(\mathbf{r},t)} \right|_{\mathbf{A}=0} = e \sum_{LL',\mathbf{k},\sigma} v_{\mathbf{k}\alpha}^{LL'} c_{\mathbf{k}L'\sigma}^\dagger c_{\mathbf{k}L\sigma}, \quad (8)$$

$$j_{\alpha\beta}^{(2)} \equiv \left. \frac{\delta^2 H}{\delta A_\alpha(\mathbf{r},t) \delta A_\beta(\mathbf{r},t)} \right|_{\mathbf{A}=0} = e^2 \sum_{LL',\mathbf{k},\sigma} v_{\mathbf{k}\alpha\beta}^{LL'} c_{\mathbf{k}L'\sigma}^\dagger c_{\mathbf{k}L\sigma}, \quad (9)$$

where

$$\begin{aligned}
 v_{\mathbf{k}\alpha}^{LL'} &\equiv i \sum_{i-j} t_{ij}^{L'L} (R_{iL'\alpha} - R_{jL\alpha}) \\
 &\quad \times \exp[-i\mathbf{k}(\mathbf{R}_i - \mathbf{R}_j)]
 \end{aligned} \quad (10)$$

and

$$\begin{aligned}
 v_{\mathbf{k}\alpha\beta}^{LL'} &\equiv (i)^2 \sum_{i-j} t_{ij}^{L'L} (R_{iL'\alpha} - R_{jL\alpha})(R_{iL'\beta} - R_{jL\beta}) \\
 &\quad \times \exp[-i\mathbf{k}(\mathbf{R}_i - \mathbf{R}_j)]. \quad (11)
 \end{aligned}$$

With Fourier transform of the band Hamiltonian (6) we can reexpress the generalized velocities resulting from Eq. (10) according to

$$v_{\mathbf{k}\alpha}^{LL'} = [\partial_{k_\alpha} - i(\rho_{L'}^\alpha - \rho_L^\alpha)] H_{\mathbf{k},LL'}^{(0)} \quad (12)$$

and Eq. (11) leads to

$$\begin{aligned}
 v_{\mathbf{k}\alpha\beta}^{LL'} &= [\partial_{k_\alpha} \partial_{k_\beta} + i(\rho_{L'}^\alpha - \rho_L^\alpha) \partial_{k_\beta} + i(\rho_{L'}^\beta - \rho_L^\beta) \partial_{k_\alpha} \\
 &\quad - (\rho_{L'}^\alpha - \rho_L^\alpha)(\rho_{L'}^\beta - \rho_L^\beta)] H_{\mathbf{k},LL'}^{(0)}. \quad (13)
 \end{aligned}$$

We will use these general expressions for the particular case of graphene, in a single-band approximation ( $\pi$  bands only) taking into account only the nearest-neighbor ( $t$ ) and the next-nearest-neighbor ( $t'$ ) hopping parameters [17]; the latter can be important since it breaks the electron-hole symmetry of the Hamiltonian which as we will see is essential for SHG.

There are two contributions to the electric current quadratic in the vector potential  $\mathbf{A}(\mathbf{r},t)$ . Note that we now switch to the response of an electric field by using the identity

$$\frac{1}{c} A_\alpha(\mathbf{r},t) = -i \frac{E_\alpha(\mathbf{r},t)}{\omega}. \quad (14)$$

The contributions to the nonlinear optical conductivity (1) via Feynman diagrams are drawn in Fig. 2.

The corresponding algebraic equation for the triangle diagram is given by

$$\begin{aligned}
 \chi_{\alpha\beta\gamma}^{\text{triangle}}(i\omega, i\omega, 2i\omega) \\
 &= -i \frac{e^3}{\omega^2} \frac{1}{\beta} \sum_{\nu} \sum_{\mathbf{k}} \sum_{L_1, \dots, L_6} v_{\mathbf{k}\alpha}^{L_6 L_1} G_{L_1 L_2}(\mathbf{k}, i\nu) \\
 &\quad \times v_{\mathbf{k}\beta}^{L_2 L_3} G_{L_3 L_4}(\mathbf{k}, i\nu + i\omega) v_{\mathbf{k}\gamma}^{L_4 L_5} G_{L_5 L_6}(\mathbf{k}, i\nu - i\omega), \quad (15)
 \end{aligned}$$

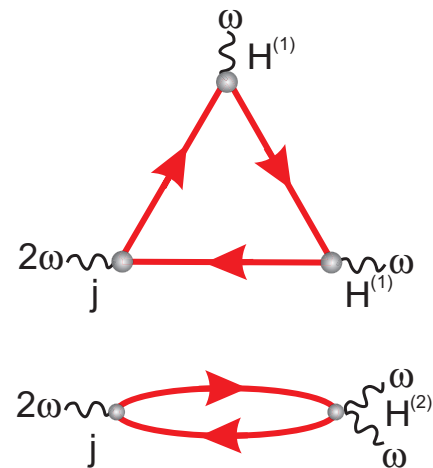


FIG. 2. (Color online) Two second-order contributions to the nonlinear susceptibility. Top: triangle diagram. Bottom: nonlinear bubble diagram. Solid lines are electron Green's functions and wavy tails indicate photons involved in the processes.

and for the nonlinear bubble diagram

$$\begin{aligned} \chi_{\alpha\beta\gamma}^{\text{bubble}}(i\omega, i\omega, 2i\omega) \\ = -i \frac{e^3}{\omega^2} \frac{1}{\beta} \sum_{\nu} \sum_{\mathbf{k}} \sum_{L_1, \dots, L_4} \\ \times v_{\mathbf{k}\alpha\beta}^{L_4 L_1} G_{L_1 L_2}(\mathbf{k}, i\nu - i\omega) v_{\mathbf{k}\gamma}^{L_2 L_3} G_{L_3 L_4}(\mathbf{k}, i\nu + i\omega). \end{aligned} \quad (16)$$

Here  $L_1, \dots, L_6$  are pseudospin indices,  $\beta = 1/T$  is the inverse temperature (we use the units  $\hbar = k_B = 1$ ), and

$$\widehat{G}(i\nu) = \frac{1}{i\nu + \mu - \widehat{H}} \quad (17)$$

is the Green's function with  $\mu$  being the chemical potential counted from the neutrality (conical) point. Thus, the nonlinear susceptibility is given by

$$\chi_{\alpha\beta\gamma} = \chi_{\alpha\beta\gamma}^{\text{bubble}} + \chi_{\alpha\beta\gamma}^{\text{triangle}}. \quad (18)$$

Note that the minus sign from the fermion loop should be taken into account in both diagrams. The factor  $\frac{1}{\omega^2}$  appears due to Eq. (14). We pass, as usual [18] to imaginary (Matsubara) frequencies; at the end of the calculations the analytical continuation to the real axis  $i\omega \rightarrow \omega + i\delta$  is performed.

If we take into account electron-electron interactions the nonlinear conductivity will be renormalized by three-leg and six-leg electron vertices; the corresponding expressions can be found in Ref. [19].

It is obvious by inversion symmetry that for the non-valley-polarized case  $\hat{\chi} = 0$ . We mimic the valley polarization by splitting the Brillouin zone into two symmetrically chosen parts, one containing the point  $K$  and the other part containing the point  $K'$ , and assuming different chemical potentials for these two parts. We then expand all the quantities dependent on the chemical potential as

$$f(\mu + \delta\mu) - f(\mu - \delta\mu) \approx 2 \frac{\partial f(\mu)}{\partial \mu} \delta\mu. \quad (19)$$

We evaluated the derivative  $\partial\chi/\partial\delta\mu$  analytically using Eqs. (15) and (16) and then performed a numerical summation over Matsubara frequencies and wave vectors involving half of the Brillouin zone. We choose  $\beta = 40/\text{eV}$ , which corresponds to a temperature of 290 K. In this case, sampling of the Brillouin with  $121 \times 121$   $k$  points and summation of 200 (1000) fermionic Matsubara frequencies are required to reach convergence for the triangle (nonlinear bubble) diagram at bosonic Matsubara frequencies  $\Omega_n = 2\pi n/\beta$  in the range of  $n = 1, \dots, 20$ .

A symmetry analysis shows that there are only two independent components of the tensor  $\hat{\chi}$ ,  $\chi_{xxx} = -\chi_{xyy} = -\chi_{yyx} = -\chi_{yxx}$  and  $\chi_{yyy} = -\chi_{yxx} = -\chi_{xxy} = -\chi_{xyx}$  [10]. With the choice of coordinates made here, the  $K$  and  $K'$  points of the Brillouin zone are on the positive/negative  $x$  axis (see Fig. 1). Thus valley polarization breaks inversion symmetry with respect to the  $x$  direction,  $x \rightarrow -x$ , but the  $y \rightarrow -y$  symmetry is preserved. Thus, we have  $\chi_{yyy} = 0$  and we will show the results only for  $\chi_{xxx}$ .

The computational results for the case of finite chemical potential  $\mu = 0.2t$  are shown in Fig. 3. For the case  $\mu = 0, t' = 0$  one finds  $d\chi_{xxx}/d\mu = 0$ , due to electron-hole symmetry. Nearest-neighbor hopping  $t'$  breaks this symmetry and leads

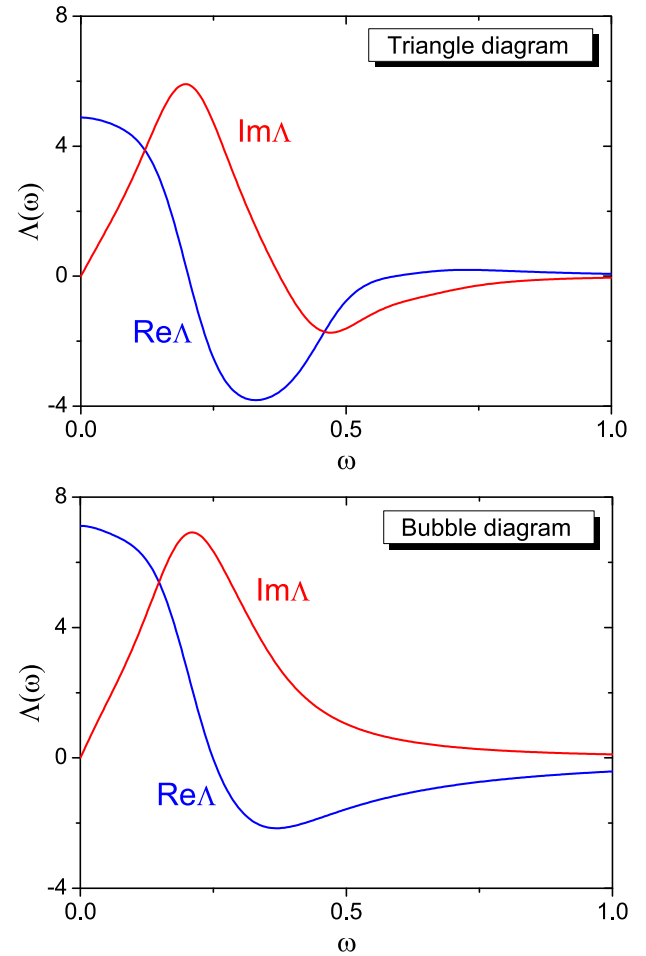


FIG. 3. (Color online) Computational results for  $\Lambda = -(\hbar\omega)^2 \frac{\partial \chi_{xxx}}{\partial \mu}$  (in the units of  $e^3 a/\hbar$ ,  $a$  is the lattice constant) as a function of real frequency  $\omega$  (in the units of  $t/\hbar$ ). The total answer is the sum of the triangle and bubble contributions.

to nonzero  $d\chi_{xxx}/d\mu$  even at  $\mu = 0$  and according to Ref. [17] we have  $t' \approx 0.1t$ . Our calculations show, however, that for  $\mu = 0.2t$  the effects of finite  $t'$  are negligible leading only to a few-percent corrections.

One can see from Fig. 3 that a dimensionless quantity  $\Lambda$  characterizing the valley-polarization induced SHG is pretty large, of the order of ten, despite the smallness of the ratios  $t'/t$  and  $\mu/t$ . It is consistent with the computational results [20–22] on SHG in chiral nanotubes which turned out to be strongly enhanced in comparison with conventional materials without inversion symmetry. A comparison with the results of Ref. [14] shows that the valley-polarization induced SHG will be dominant if  $|\delta\mu|/t > 0.01v_F/c \approx 3 \times 10^{-5}$ . Note, that one additional smallness in order of magnitude originates from the factor  $3/8\pi \approx 0.1$  in Ref. [14] and another one from the fact that  $\Lambda \approx 10$ .

Typical nonlinear crystals have second-order nonlinear susceptibilities on the order of  $\tilde{\chi} = 0.1$  to 100 pm/V [10]. It is interesting to see which amount of valley polarization is required to reach this order in graphene. From the current density  $j = \chi E^2$  we obtain the oscillating in-plane charge density  $|\sigma| = |j|/c$  and the associated

electric field  $E_{2\omega} = \sigma/\epsilon_0 = \chi E^2/\epsilon_0 c = \tilde{\chi} E^2$ . With photon energies on the order of  $\hbar\omega = 1.5 \text{ eV} \approx 0.5t$  and  $\Lambda \approx 10$  we find thus  $\tilde{\chi}/\delta\mu = -\Lambda(e^3 a/\hbar)/[\epsilon_0 c(\hbar\omega)^2] \approx 1(\text{\AA}/\text{V})/\text{eV} = 100 \text{ (pm/V)/eV}$ . Thus  $\delta\mu \gtrsim 1 \text{ meV}$  is required to reach  $\tilde{\chi} = 0.1 \text{ pm/V}$ .

This means that SHG is, indeed, a very efficient tool to probe the valley polarization in graphene. Our results show that “triangle” and “bubble” contributions to the second-harmonic generation are, in general, comparable. Also, one can see that they have quite a similar frequency dependence. An alternative way to probe the valley polarization is the photogalvanic effect, that is, generation of dc current under laser pulses. This process is described by the quantity  $\chi_{\alpha\beta\gamma}(\omega, \omega, 0)$  which is of the same order of magnitude as  $\chi_{\alpha\beta\gamma}(\omega, \omega, 2\omega)$  calculated here. It would be very interesting to probe both of these effects experimentally in graphene with valley polarization.

In monolayer MoS<sub>2</sub>, valley polarization is controllable by (linear) optics [11,12]. Symmetry-wise MoS<sub>2</sub> corresponds to graphene with broken sublattice symmetry (i.e.,  $D_{3h}$ ), where Mo atoms occupy sublattice *A* and the S atoms reside on sublattice *B*. Thus, there is no  $y \rightarrow -y$  mirror symmetry and  $\chi_{yyy} \neq 0$  even in the absence of valley polarization. The initial  $x \rightarrow -x$  mirror symmetry of MoS<sub>2</sub> ensures, however, that nonzero  $\chi_{xxx}$  requires additional symmetry break as provided, e.g., by valley polarization. Thus, the concept of nonlinear optics and photogalvanic effects to detect valley polarization is partly transferable to MoS<sub>2</sub>. It works with light

which is linearly polarized in the  $x$  direction but not in the  $y$  direction.

Lattice matched graphene-hBN (hexagonal boron nitride) heterostructures have proven to allow for nonlocal transport phenomena based on the valley degree of freedom over micron scale distances [15]. It appears thus highly promising to combine the advantages of MoS<sub>2</sub> (optical generation of valley polarization [11,12]) with those of graphene (transport properties). Finally, for graphene (not lattice matched to hBN) very close to the neutrality point a flavor Hall effect has been observed which could be of spin or valley origin [23]. Measuring SHG could solve this puzzle, since only valley but not spin polarization would lead to an SHG signal.

*Note added.* Recently, a related work, Ref. [24], reporting similar results has been published. While Ref. [24] focuses on lower energies (the authors of that work use Dirac spectrum with trigonal warping corrections, instead of the full tight-binding spectrum as in the present work), the conclusions drawn here and in Ref. [24] are in agreement.

The authors acknowledge financial support from European Union Seventh Framework Program under grant agreement Graphene Flagship and the Deutsche Forschungsgemeinschaft (DFG) through SPP 1459. M.I.K. also acknowledges financial support from the European Research Council Advanced Grant program (Contract No. 338957).

- 
- [1] A. K. Geim and K. S. Novoselov, *Nat. Mater.* **6**, 183 (2007).  
 [2] A. H. Castro Neto, F. Guinea, N. M. R. Peres, K. S. Novoselov, and A. K. Geim, *Rev. Mod. Phys.* **80**, 315 (2008).  
 [3] M. I. Katsnelson, *Graphene: Carbon in Two Dimensions* (Cambridge University Press, Cambridge, 2012).  
 [4] A. Rycerz, J. Tworzydło, and C. W. J. Beenakker, *Nat. Phys.* **3**, 172 (2007).  
 [5] I. Žutić, J. Fabian, and S. Das Sarma, *Rev. Mod. Phys.* **76**, 323 (2004).  
 [6] I. Martin, Y. M. Blanter, and A. F. Morpurgo, *Phys. Rev. Lett.* **100**, 036804 (2008).  
 [7] L. E. Golub, S. A. Tarasenko, M. V. Entin, and L. I. Magarill, *Phys. Rev. B* **84**, 195408 (2011).  
 [8] Y. Jiang, T. Low, K. Chang, M. I. Katsnelson, and F. Guinea, *Phys. Rev. Lett.* **110**, 046601 (2013).  
 [9] A. R. Akhmerov and C. W. J. Beenakker, *Phys. Rev. Lett.* **98**, 157003 (2007).  
 [10] R. W. Boyd, *Nonlinear Optics* (Academic, New York, 1992).  
 [11] H. Zeng, J. Dai, W. Yao, D. Xiao, and X. Cui, *Nat. Nanotechnol.* **7**, 490 (2012).  
 [12] K. F. Mak, K. He, J. Shan, and T. F. Heinz, *Nat. Nanotechnol.* **7**, 494 (2012).  
 [13] A. Kirilyuk, A. V. Kimel, and T. Rasing, *Rev. Mod. Phys.* **82**, 2731 (2010).  
 [14] S. A. Mikhailov, *Phys. Rev. B* **84**, 045432 (2011).  
 [15] R. V. Gorbachev, J. C. W. Song, G. L. Yu, A. V. Kretinin, F. Withers, Y. Cao, A. Mishchenko, I. V. Grigorieva, K. S. Novoselov, L. S. Levitov, and A. K. Geim, *Science* **346**, 448 (2014).  
 [16] T. Stauber, N. M. R. Peres, and A. K. Geim, *Phys. Rev. B* **78**, 085432 (2008).  
 [17] A. Kretinin, G. L. Yu, R. Jalil, Y. Cao, F. Withers, A. Mishchenko, M. I. Katsnelson, K. S. Novoselov, A. K. Geim, and F. Guinea, *Phys. Rev. B* **88**, 165427 (2013).  
 [18] G. Mahan, *Many-Particle Physics* (Plenum, New York, 2000).  
 [19] M. I. Katsnelson and A. I. Lichtenstein, *J. Phys.: Condens. Matter* **22**, 382201 (2010).  
 [20] G. Y. Guo, K. C. Chu, D.-S. Wang, and C.-G. Duan, *Phys. Rev. B* **69**, 205416 (2004).  
 [21] J. Zhou, H. Weng, G. Wu, and J. Dong, *Appl. Phys. Lett.* **89**, 013102 (2006).  
 [22] T. G. Pedersen and K. Pedersen, *Phys. Rev. B* **79**, 035422 (2009).  
 [23] D. A. Abanin, S. V. Morozov, L. A. Ponomarenko, R. V. Gorbachev, A. S. Mayorov, M. I. Katsnelson, K. Watanabe, T. Taniguchi, K. S. Novoselov, L. S. Levitov, and A. K. Geim, *Science* **332**, 328 (2011).  
 [24] L. E. Golub and S. A. Tarasenko, *Phys. Rev. B* **90**, 201402(R) (2014).